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ON Semiconductor[®]



ASM3P2872A

Peak EMI Reducing Solution

Features

- Generates an EMI optimized clock signal at the output.
- Integrated loop filter components.
- Operates with a 3.3V / 2.5V supply.
- Operating current less than 6mA.
- CMOS design.
- Input frequency range: 13MHz to 30MHz for 2.5V 13MHz to 30MHz for 3.3V
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Frequency deviation: -1.25% @ 22MHz.
- Available in 6L-TSOP (6L-TSOT-23) packages.

Product Description

The ASM3P2872A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2872A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2872A allows significant system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

The ASM3P2872A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

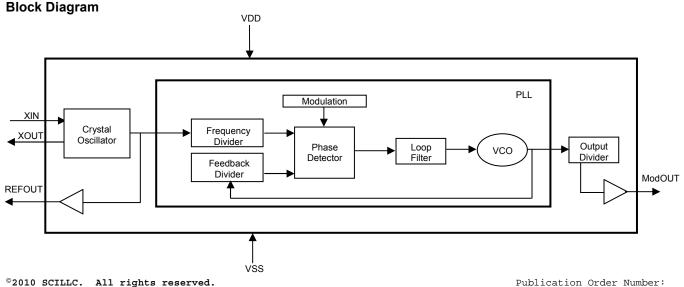
The ASM3P2872A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This results in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation.'

Applications

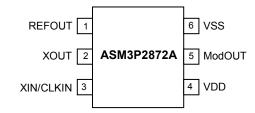
The ASM3P2872A is targeted towards all portable devices like MP3 players, Notebooks and digital still cameras.

Key Specifications

Description	Specification
Supply voltages	VDD = 3.3V /2.5V
Cycle-to-Cycle Jitter	±200pS (Typ)
Output Duty Cycle	45/55% (worst case)
Modulation Rate Equation	F _{IN} /640
Frequency Deviation	-1.25% @ 22MHz



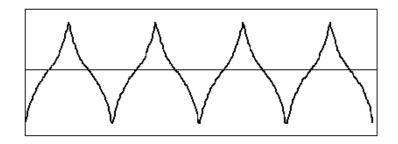
Pin Configuration (6L-TSOP Package)



Pin Description

Pin#	Pin Name	Туре	Description			
1	REFOUT	0	Buffered output of the input frequency.			
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.			
3	XIN / CLKIN	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.			
4	VDD	Р	Power supply for the entire chip.			
5	ModOUT	0	Spread spectrum clock output.			
6	VSS	Р	Ground connection.			

Modulation Profile



Specifications

Description		Specification
	For 2.5V Supply	13MHz < CLKIN < 30MHz
Frequency Range	For 3.3V Supply	13MHz < CLKIN < 30MHz
Modulation Equation		F _{IN} /640
Frequency Deviation		-1.25% @ 22MHz

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit				
VDD, V _{IN}	Voltage on any pin with respect to Ground	-0.5 to +4.6	V				
T _{STG}	Storage temperature	-65 to +125	C				
Ts	Max. Soldering Temperature (10 sec)	260	C				
TJ	Junction Temperature	150	C				
T _{DV}	T _{DV} Static Discharge Voltage (As per JEDEC STD22- A114-B) 2 KV						
	Note: These are stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings for prolonged periods of time may affect device reliability.						

Operating Conditions

Parameter	Description	Min	Max	Unit
VDD	Supply Voltage	2.375	3.6	V
T _A	Operating Temperature (Ambient Temperature)	0	70	C
CL	Load Capacitance		15	pF
CIN	Input Capacitance		7	pF

DC Electrical Characteristics for 2.5V Supply

Symbol	Parameter	Min	Тур	Max	Unit
V _{IL}	Input low voltage	VSS-0.3		0.8	V
VIH	Input high voltage	2.0		VDD+0.3	V
I _{IL}	Input low current			-35	μA
I _{IH}	Input high current			35	μA
I _{XOL}	XOUT output low current (@ 0.5V, VDD = 2.5V)		3		mA
I _{XOH}	XOUT output high current (@ 1.8V, VDD = 2.5V)		3		mA
V _{OL}	Output low voltage (VDD = 2.5 V, I _{OL} = 8mA)			0.6	V
V _{OH}	Output high voltage (VDD = 2.5 V , $I_{OH} = 8\text{mA}$)	1.8			V
I _{DD}	Static supply current ¹		1.1		mA
Icc	Dynamic supply current (2.5V, 30MHz and with no load)		4.0		mA
VDD	Operating voltage	2.375	2.5	2.625	V
t _{on}	Power-up time (first locked cycle after power-up)			5	mS
Z _{OUT}	Output impedance		50		Ω
Note: 1. XIN /	CLKIN pin is pulled low.				

Symbol	Pa	Min	Тур	Max	Unit	
CLKIN	Input frequency		13		30	MHz
ModOUT	Output frequency		13		30	MHz
f	Fraguency Deviation	Input Frequency = 13MHz		-1.85		%
f _d	Frequency Deviation	Input Frequency = 30MHz		-0.9		
t _{LH} 1	Output rise time (measured from 0.7V to 1.7V)		0.7	1.5	1.7	nS
t _{HL} 1	Output fall time (measured from 1.7V to 0.7V)		0.5	0.9	1.1	nS
t _{JC}	Jitter (cycle-to-cycle)			±200		pS
t _D	Output duty cycle	45	50	55	%	
Note: 1. t_{LH} and t_{HL}	are measured into a capacitive	oad of 15pF.		•		

AC Electrical Characteristics for 2.5V Supply

DC Electrical Characteristics for 3.3V Supply

Symbol	Parameter	Min	Тур	Мах	Unit
VIL	Input low voltage	VSS-0.3		0.8	V
VIH	Input high voltage	2.0		VDD+0.3	V
IIL	Input low current			-35	μA
I _{IH}	Input high current			35	μA
I _{XOL}	XOUT output low current (@ 0.4V, VDD = 3.3V)		3		mA
I _{XOH}	XOUT output high current (@ 2.5V, VDD = 3.3V)		3		mA
V _{OL}	Output low voltage (VDD = 3.3 V, I _{OL} = 8mA)			0.4	V
V _{OH}	Output high voltage (VDD = 3.3 V , $I_{OH} = 8 \text{mA}$)	2.5			V
I _{DD}	Static supply current ¹		1.2		mA
Icc	Dynamic supply current (3.3V, 30MHz and with no load)		5.5		mA
VDD	Operating voltage	2.7	3.3	3.6	V
t _{on}	Power-up time (first locked cycle after power-up)			5	mS
Zout	Output impedance		45		Ω
Note: 1. XIN	CLKIN pin is pulled low.	·		•	

Symbol	Pa	Min	Тур	Мах	Unit				
CLKIN	Input frequency		13		30	MHz			
ModOUT	Output frequency		13		30	MHz			
£	Input Frequency = 13MHz Input Frequency = 30MHz	Input Frequency = 13MHz		-1.85		0/			
f _d			-0.9		%				
t _{LH} 1	Output rise time (measu	Output rise time (measured from 0.8 to 2.0V)		1.4	1.7	nS			
t _{HL} ¹	Output fall time (measur	Output fall time (measured at 2.0V to 0.8V)		0.9	1.1	nS			
t _{JC}	Jitter (cycle-to-cycle)	Jitter (cycle-to-cycle)		±200		pS			
t _D	Output duty cycle		45	50	55	%			
Note: 1. t_{LH} and t_{HL} are	measured into a capacitive load of	f 15pF.	•	Note: 1. t _{LH} and t _{HL} are measured into a capacitive load of 15pF.					

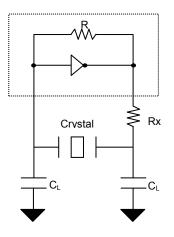
AC Electrical Characteristics for 3.3V Supply

Typical Crystal Specifications

Fundamental AT cut parallel resonant crystal			
Nominal frequency	14.31818MHz		
Frequency tolerance	± 50 ppm or better at 25℃		
Operating temperature range	-25℃ to +85℃		
Storage temperature	-40℃ to +85℃		
Load capacitance(C _P)	18pF		
Shunt capacitance	7pF maximum		
ESR	25 Ω		

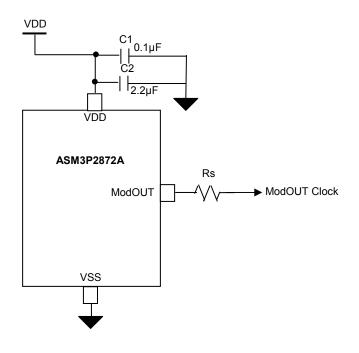
Note: Note: C_L is Load Capacitance and Rx is used to prevent oscillations at overtone frequency of the Fundamental frequency.

Typical Crystal Interface Circuit



 $C_L = 2^*(C_P - C_S), \\ Where C_P = Load capacitance of crystal \\ C_S = Stray capacitance due to C_{IN,} PCB, Trace etc.$

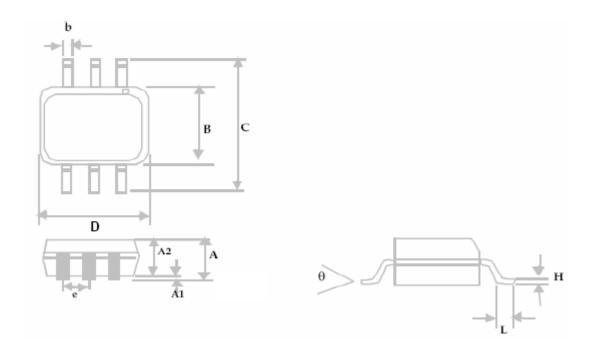
Typical Application Schematic



ASM3P2872A

Package Information

6L-TSOP Package



	Dimensions				
Symbol	Inches		Millim	neters	
	Min	Max	Min	Max	
А		0.04		1.00	
A1	0.00	0.004	0.00	0.10	
A2	0.033	0.036	0.84	0.90	
b	0.012	0.02	0.30	0.50	
н	0.005	5 BSC	0.127	BSC	
D	0.114	BSC	2.90	BSC	
В	0.06	BSC	1.60	BSC	
е	0.0374 BSC		0.950	BSC	
С	0.11	BSC	2.80 BSC		
L	0.0118	0.02	0.30	0.50	
θ	0°	4°	0°	4°	

Ordering Information

Part Number	Marking	Package Type	Temperature
ASM3P2872AF-06OR	B4L	6L-TSOP (6L-TSOT-23), TAPE & REEL, Pb Free	0℃ to +70℃

A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-free.

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